

### An updated member in the family of Silicon-based reflection trap detector

Since the beginning of the present year our production list of photodetectors was enriched. We have developed a new 3-element trap detector which is based on large-area windowless silicon photodiodes type S1337-21 from Hamatsu. The outer dimensions of the photodiodes are 25,4 x 25,4 mm with the active area of 18x18 mm.

As it is our business, we have designed the trap detector as compact as possible: the outer diameter is 80 mm and the length of the housing is 66 mm with BNC connector (Figure 1).

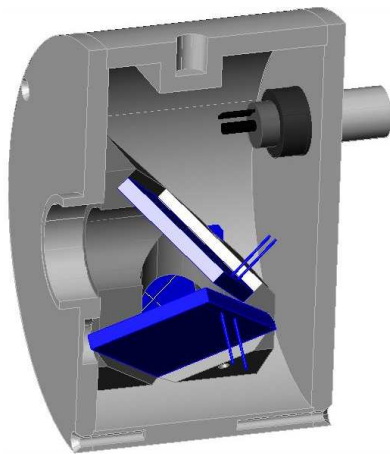


Figure 1. Schematic cross-section of the large-area photodiode trap detector HHL03-S1337. Photodiodes are seen in blue colour.

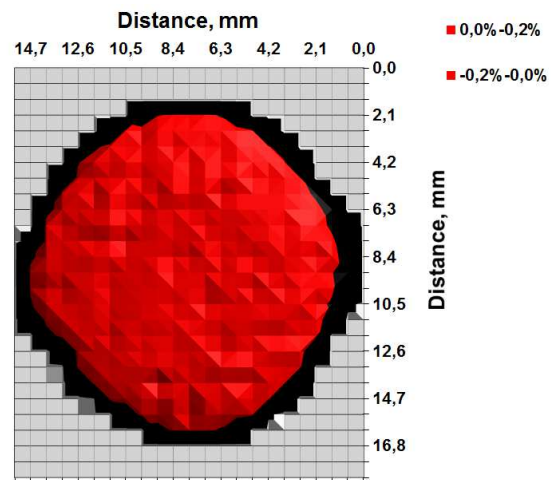


Figure 2. The active area of the trap detector HHL03-S1337 measured at 633-nm laser wavelength.

The compact design assures the shortest optical path length of 99 mm providing large field of view 18 °. As compared to the ordinary small-area photodetector, the active area of the large-area reflection photodetector is more than 3 times larger, ie 183 mm (Figure 2).

Owing to fruitful co-operation with Chinese and Korean colleagues the performance of the new trap detector HHL03-S1337 was tested in the visible wavelength range. The results were as good as for the conventional trap detector consisting of small-area photodiodes. Both, the reflectance and the responsivity values are comparable to those of small-area 3-element trap detector based on windowless photodiodes type S1337-11 from Hamamatsu.

As an example, the calculated responsivity values are compared to those of measured values in the wavelength range from 457 nm to 950 nm in Figure 3.

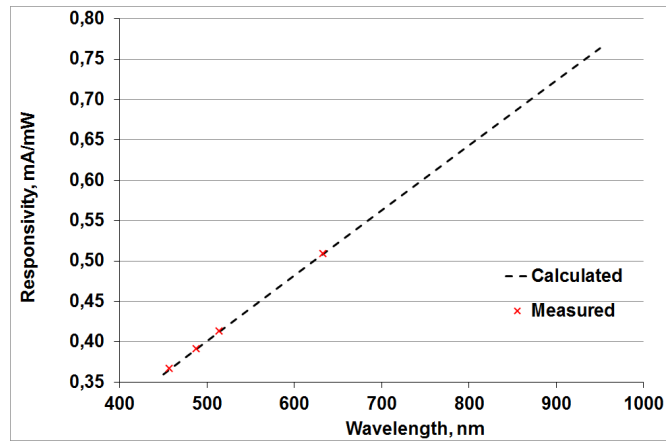


Figure 3. Responsivity of the large-area photodiode trap detector HHL03-S1337.

The new large-area trap detector exhibits excellent reflectance, as well as, responsivity modelling properties and is very useful in weak radiation measurements emitted in large beams.